Onsemi

MARKING DIAGRAMS

TinyLogic UHS Triple Inverter with Schmitt Trigger Input

NC7NZ14

Description

The NC7NZ14 is a triple inverter with Schmitt trigger input from onsemi's Ultra-High Speed (UHS) series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a very broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} range. The inputs and outputs are high-impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V independent of V_{CC} operating voltage.

Features

- Ultra High-Speed: $t_{PD} = 3.7$ ns (Typical) into 50 pF at 5 V V_{CC}
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Power Down High Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra-Small MicroPakTM Packages
- Space–Saving US8 Surface Mount Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

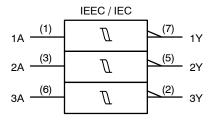


Figure 1. Logic Symbol

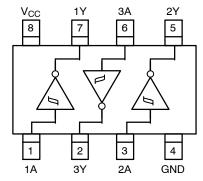
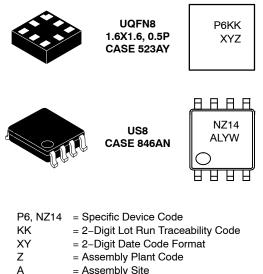


Figure 2. Connection Diagram (Top View)



= Assembly Site

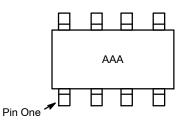
L

- = Wafer Lot Number
- YW = Assembly Start Week

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 6 of this data sheet.

Pin Configurations



NOTES:

- AAA represents product code top mark (see ordering table).
 Orientation of top mark determines pin one location. Reading the top product code mark left to right, pin one is the lower left pin.

Figure 3. US8

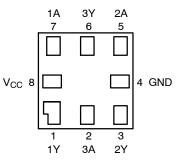


Figure 4. MicroPak (Top Through View)

PIN DEFINITIONS

Pin # US8	Pin # MicroPak	Name	Description			
1	7	1A	Input			
2	6	ЗY	Output			
3	5	2A	Input			
4	4	GND	Ground			
5	3	2Y	Output			
6	2	ЗA	Input			
7	1	1Y	Output			
8	8	V _{CC}	Supply Voltage			

FUNCTION TABLE

Input	Output
A	Y
L	Н
Н	L

H = HIGH Logic Level L = LOW Logic Level

ABSOLUTE MAXIMUM RATINGS

Symbol	Paran	neter	Min	Мах	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
Ι _{ΙΚ}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
Ι _{ΟΚ}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Current		-	±50	mA
I _{CC} / I _{GND}	DC V _{CC} or Ground Current		-	±50	mA
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature Under Bia	S	-	+150	°C
ΤL	Junction Lead Temperature (Sole	dering, 10 Seconds)	-	+260	°C
PD	Power Dissipation in Still Air US8		-	500	mW
		MicroPak-8	-	539	
ESD	Human Body Model, JEDEC: JESD22-A114		-	4000	V
	Charge Device Model, JEDEC:	arge Device Model, JEDEC: JESD22-C101		2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.5	5.5	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
θ_{JA}	Thermal Resistance	US8	-	250	°C/W
		MicroPak-8	-	232	1

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

3. Unused inputs must be held HIGH or LOW. They may not float.

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DC ELECTICAL CHARACTERISTICS

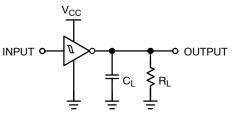
					T _A = +25°C		T _A = -40	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
VP	Positive Threshold Voltage	1.65		-	1.10	1.50	-	1.50	V
		2.30		_	1.40	1.80	-	1.80	
		3.00		_	1.75	2.20	-	2.20	
		4.50		_	2.45	3.10	-	3.10	
		5.50		_	2.90	3.60	-	3.60	
V _N	Negative Threshold Voltage	1.65		0.25	0.55	-	0.25	-	V
		2.30		0.40	0.75	-	0.40	-	
		3.00		0.60	1.00	-	0.60	-	
		4.50		1.00	1.43	-	1.00	-	
		5.50		1.20	1.70	-	1.20	-	
V_{H}	Hysteresis Voltage	1.65		0.15	0.54	1.00	0.15	1.00	V
		2.30		0.25	0.65	1.10	0.25	1.10	
		3.00		0.40	0.77	1.20	0.40	1.20	
		4.50		0.60	1.01	1.50	0.60	1.50	
		5.50		0.70	1.18	1.70	0.70	1.70	
V _{OH}	HIGH Level Output Voltage	1.65	$V_{IN} = V_P \text{ or } V_N,$	1.55	1.65	-	1.55	-	V
		2.30	I _{OH} = −100 μA	2.20	2.30	-	2.20	-	
		3.00		2.90	3.00	-	2.90	-	
		4.50		4.40	4.50	-	4.4	-	
		1.65	I _{OH} = -4 mA	1.29	1.52	-	1.29	-	
		2.30	I _{OH} = -8 mA	1.90	2.15	-	1.90	-	
		3.00	I _{OH} = -16 mA	2.40	2.80	_	2.40	-	
		3.00	I _{OH} = -24 mA	2.30	2.68	-	2.30	-	
		4.50	I _{OH} = -32 mA	3.80	4.20	-	3.80	-	
V _{OL}	LOW Level Output Voltage	1.65	$V_{IN} = V_P \text{ or } V_N,$	-	0.00	0.10	-	0.10	V
		2.30	· I _{OL} = 100 μA	-	0.00	0.10	-	0.10	
		3.00		-	0.00	0.10	-	0.10	
		4.50		-	0.00	0.10	-	0.10	
		1.65	I _{OL} = 4 mA	_	0.08	0.24	-	0.24	
		2.30	I _{OL} = 8 mA	-	0.10	0.30	-	0.30	
		3.00	I _{OL} = 16 mA	-	0.15	0.40	-	0.40	
		3.00	I _{OL} = 24 mA	-	0.22	0.55	-	0.55	
		4.50	I _{OL} = 32 mA	-	0.22	0.55	_	0.55	
I _{IN}	Input Leakage Current	1.65 to 5.5	V _{IN} = 5.5 V, GND	-	_	±0.1	_	±1.0	μA
I _{OFF}	Power Off Leakage Current	0	V _{IN} or V _{OUT} = 5.5 V	-	-	1	-	10	μA
I _{CC}	Quiescent Supply Current	1.65 to 5.50		_	-	1.0	-	10	μΑ

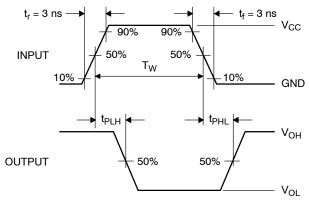
NC7NZ14

AC ELECTRICAL CHARACTERISTICS

				$T_A = +25^{\circ}C$ T_A		T _A = -40	$T_A = -40$ to $+85^{\circ}C$		
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}		1.80 ±0.15	C _L = 15 pF, R _L = 1 MΩ,	-	7.6	12.5	-	13.0	ns
	(Figure 5, 6)	2.50 ±0.20		-	5.0	9.0	-	9.5	
		$3.30\pm\!\!0.30$		-	3.7	6.3	-	6.5	
		$5.00\pm\!\!0.50$		-	3.1	5.2	-	5.5	
		$3.30\pm\!\!0.30$		-	4.4	7.2	-	7.5	
		$5.00\pm\!\!0.50$	· R _L = 500 Ω,	-	3.7	5.9	-	6.2	
C _{IN}	Input Capacitance	0.00		-	2.5	-	-	-	pF
	Power Dissipation Capacitance	3.30		-	9	-	-	-	pF
	(Note 4) (Figure 7)	5.00		-	11	-	-	-	

4. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: $I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC} static).$

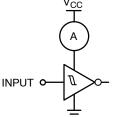




NOTE:

5. C_L includes load and stray capacitance; Input PRR = 1.0 MHz, t_W = 500 ns.

Figure 5. AC Test Circuit



NOTE:

6. Input = AC Waveform; $t_r = t_f = 1.8$ ns; PRR = 10 MHz; Duty Cycle = 50%.

Figure 7. I_{CCD} Test Circuit

Figure 6. AC Waveforms

NC7NZ14

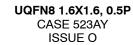
ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping [†]
NC7NZ14K8X	NZ14	8-Lead US8, JEDEC MO-187, Variation CA 3.1 mm Wide	3000 / Tape & Reel
NC7NZ14L8X	P6	8-Lead MicroPak, 1.6 mm Wide	5000 / Tape & Reel
NC7NZ14L8X-L22185	P6	8-Lead MicroPak, 1.6 mm Wide	5000 / Tape & Reel

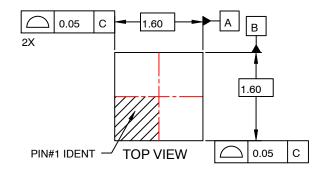
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

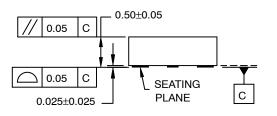
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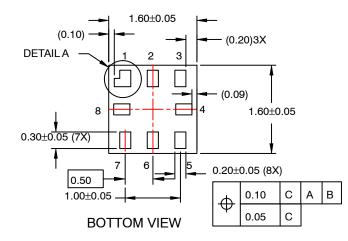


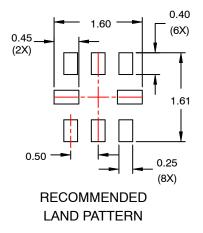
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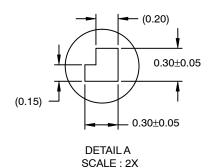
SIDE VIEW





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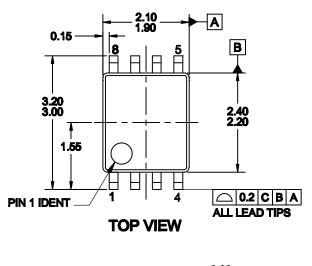
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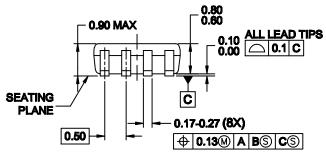
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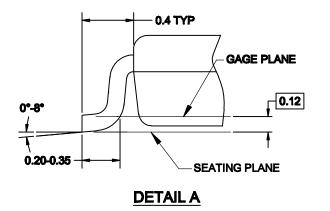
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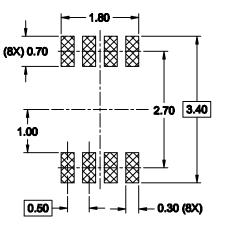
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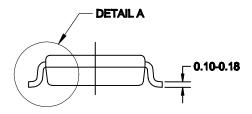




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